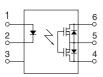
Panasonic ideas for life

Normally closed SOP6-pin type of 400V load voltage

PhotoMOS® GU SOP 1 Form B (AQV414S)

6.3 .248 .248 .248 .210 .083

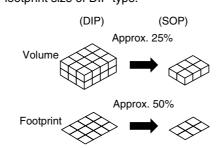
mm inch



RoHS compliant

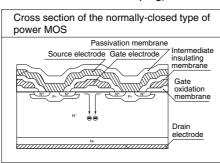
FEATURES

1. Miniature SOP6-pin package The device comes in a small SOP measuring (W) $4.4 \times$ (L) $6.3 \times$ (H) 2.1 mm (W) $.173 \times$ (L) $.248 \times$ (H) .083 inch approx. 25% of the volume and 50% of the footprint size of DIP type.



2. Low on-resistance (typ. 26 $\Omega)$ for normally-closed type

This has been achieved thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-Diffused and Selective Doping) method.



3. Controls low-level analog signals

PhotoMOS feature extremely low closedcircuit offset voltage to enable control of low-level analog signals without distortion.

4. Low-level off state leakage current of max. 1 μ A

TYPICAL APPLICATIONS

- Telephones
- Measuring instruments
- Computers
- Industrial robots
- High-speed inspection machines

TYPES

	Output rating*				Part No.	Packing quantity		
	lood lo	Load	Package	age Tube packing style	Tape and reel packing style			
	Load voltage	current	1 ackage		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube	Tape and reel
AC/DC dual use	400V	100mA	SOP6-pin	AQV414S	AQV414SX	AQV414SZ	1 tube contains: 75 pcs. 1 batch contains: 1,500 pcs.	1,000 pcs.

^{*} Indicate the peak AC and DC values.

Note: For space reasons, only "V41S" is marked on the product. The two initial letters of the part number "AQ" and the packing style indicator "X" or "Z" have been omitted.

RATING

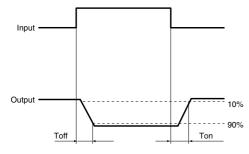
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Item	Symbol	Type of connection	AQV414S	Remarks	
	LED forward current	lF		50 mA		
Input	LED reverse voltage	VR		5 V		
	Peak forward current	IFP		1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin		75 mW		
Output	Load voltage (peak AC)	VL		400 V		
		lı	A	0.10 A	A connection: Peak AC, DC B, C connection: DC	
	Continuous load current		В	0.11 A		
			С	0.12 A		
	Peak load current	Ipeak		0.3 A	A connection: 100 ms (1 shot) V _L = DC	
	Power dissipation	Pout		450 mW		
Total power dissipation		Рт		500 mW		
I/O isolation voltage		Viso		1,500 V AC		
Temperature limits	Operating	Topr] \	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures	
	Storage	T _{stg}		-40°C to +100°C -40°F to +212°F		

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item				Type of connection	AQV414S	Remarks	
	LED operate (OFF) current	Typical	J		0.6 mA	IL= Max.	
	LED operate (OFF) current	Maximum	Foff	_	3 mA		
Innut	LED reverse (ON) current	Minimum	Fon	_	0.4 mA	IL= Max.	
Input	LED reverse (ON) current	Typical			0.55 mA	IL= IVIAX.	
	LED dropout voltage	Typical	VF	_	1.25 V (1.14 V at I _F = 5 mA)	I _F = 50 mA	
	LED dropout voltage	Maximum			1.5 V	IF= 50 MA	
		Typical		A	26 Ω	I _F = 0 mA I _L = Max. Within 1 s on time	
	On resistance	Maximum	Ron		50 Ω		
		Typical	Ron	В	20 Ω	I _F = 0 mA I _L = Max. Within 1 s on time	
Output		Maximum			25 Ω		
		Typical	Ron	С	10 Ω	I _F = 0 mA I _L = Max. Within 1 s on time	
		Maximum			12.5 Ω		
	Off state leakage current	Maximum	Leak	_	1 μΑ	$I_F = 5 \text{ mA}, V_L = \text{Max}.$	
	Onerste (OFF) time*	Typical	_		0.47 ms	I _F = 0 mA \rightarrow 5 mA V _L = Max.	
	Operate (OFF) time*	Maximum	Toff	_	1.0 ms		
- ,	Reverse (ON) time*	Typical _	Ton		0.28 ms	I _F = 5 mA \rightarrow 0 mA V_L = Max.	
Transfer characteristics	neverse (ON) time	Maximum	Ion	_	1.0 ms		
ondidoter istics	I/O capacitance	Typical	Ciso		0.8 pF	f = 1 MHz V _B = 0 V	
	і/О сараспапсе	Maximum	Ciso	_	1.5 pF		
	Initial I/C isolation resistance Minimum		Riso	_	1,000 ΜΩ	500 V DC	

^{*}Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit			
Input LED current	lF	5	mA			

- **■** For Dimensions.
- **■** For Schematic and Wiring Diagrams.
- **■** For Cautions for Use.
- These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

For more information.

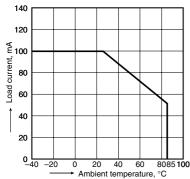
GU SOP 1 Form B (AQV414S)

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F

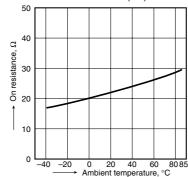
Type of connection: A



2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6; LED current: 0 mA;

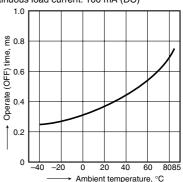
Continuous load current: 100 mA (DC)



3. Operate (OFF) time vs. ambient temperature characteristics

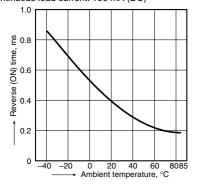
LED current: 5 mA; Load voltage: 400 V (DC);

Continuous load current: 100 mA (DC)



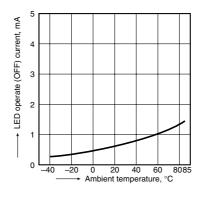
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 50 mA; Load voltage: 400 V (DC); Continuous load current: 100 mA (DC)



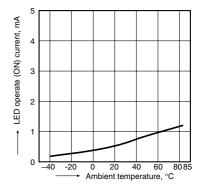
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: 400 V (DC); Continuous load current: 100 mA (DC)

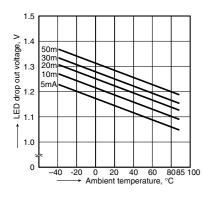


6. LED reverse (ON) current vs. ambient temperature characteristics Load voltage: 400 V (DC);

Continuous load current: 100 mA (DC)

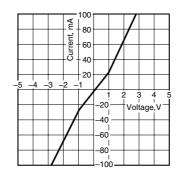


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



8. Current vs. voltage characteristics of output at MOS portion

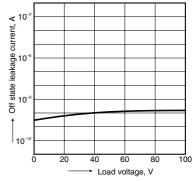
Measured portion: between terminals 4 and 6; Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6; LED current: 5 mA;

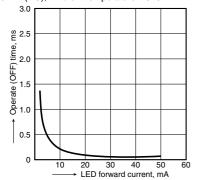
Ambient temperature: 25°C 77°F



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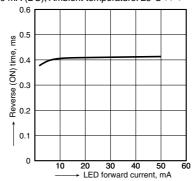
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: 400 V (DC); Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: 400 V (DC); Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6; Frequency: 1 MHz;

Ambient temperature: 25°C 77°F

